
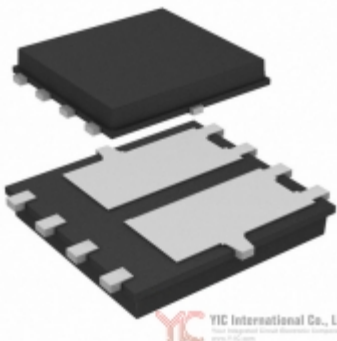
	<h2>SI7904DN-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI7904DN-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2N-CH 20V 5.3A 1212-8</p> <p>Datenblätter:  SI7904DN-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 6000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7904DN-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2N-CH 20V 5.3A 1212-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	6000 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.3W
Verpackung / Gehäuse	PowerPAK® 1212-8 Dual
Supplier Device-Gehäuse	PowerPAK® 1212-8 Dual
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	5.3A
Rds On (Max) @ Id, Vgs	30 mOhm @ 7.7A, 4.5V
VGS (th) (Max) @ Id	1V @ 935µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI7904DN-T1-GE3 ist neu im Original, Suche SI7904DN-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7904DN-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7904DN-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7904DN V SI7904DN V</p>	 <p>SI7905DN-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 40V 6A 1212-8</p>	 <p>SI7905DN-T1-E3 Vishay / Siliconix MOSFET 2P-CH 40V 6A 1212-8</p>	 <p>SI7904DN-T1-E3 Vishay / Siliconix MOSFET 2N-CH 20V 5.3A 1212-8</p>
 <p>SI7904DN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 5.3A 1212-8</p>	 <p>SI7904DN-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 5.3A 1212-8</p>	 <p>SI7904DN.. V V QFN8</p>	 <p>SI7905DN-T1-GE3 Vishay / Siliconix MOSFET 2P-CH 40V 6A PPAK 1212-8</p>

heiße Teile

Mehr

- | | | | | |
|--|--|---|---|--|
|  SI7898DP-T1-GE3 |  SI7898DP-T1-GE3 |  SI7900ADN |  SI7900AEDN |  SI7900AEDN-T1 |
|  SI7900AEDN-T1-E3 |  SI7900AEDN-T1-E3 |  SI7900AEDN-T1-GE3 |  SI7900AEDN-T1-GE3 |  SI7900EDN |
|  SI7900EDN-T1 |  SI7900EDN-T1-E3 |  SI7900EDN-T1-GE3 |  SI7901EDN-T1 |  SI7901EDN-T1-E3 |
|  SI7901EDN-T1-E3 |  SI7904BDN-T1-E3 |  SI7904BDN-T1-E3 |  SI7904BDN-T1-GE3 |  SI7904BDN-T1-GE3 |
|  SI7904DN |  SI7904DN-T1 |  SI7904DN-T1-E3 |  SI7904DN-T1-E3 |  SI7904DN-T1-GE3 |
|  SI7905DN-T1-GE3 |  SI7905DN-T1-GE3 |  SI7909DN-T1-E3 |  SI7909DN-T1-E3 |  SI7909DN-T1-GE3 |
|  SI7909DN-T1-GE3 |  SI7911DN |  SI7911DN-T1-E3 |  SI7911DN-T1-E3 |  SI7911DN-T1-GE3 |
|  SI7911DN-T1-GE3 |  SI7913DN-T1-E3 |  SI7913DN-T1-E3 |  SI7913DN-T1-GE3 |  SI7913DN-T1-GE3 |
|  SI7922DN-T1-E3 |  SI7922DN-T1-E3 |  SI7922DN-T1-GE3 |  SI7922DN-T1-GE3 |  SI7923DN-T1-E3 |
|  SI7923DN-T1-E3 |  SI7923DN-T1-GE3 |  SI7923DN-T1-GE3 |  SI7938DP-T1-GE3 |  SI7938DP-T1-GE3 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited